

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent No7,160,817 B2
Patent Issue Date January 9, 2007
Application Serial No.09/945,393
Filing Date August 30, 2001
Assignee Micron Technology, Inc.
Inventorship..... Marsh
Attorney's Docket No.MI22-1728
Title: Dielectric Material Forming Methods and Enhanced Dielectric Materials

**REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT FOR
APPLICANT MISTAKES and PTO MISTAKES (37 C.F.R. §§ 1.322(a) and 1.323)**

To: Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450
ATTN: Decision and Certificate of Correction
Branch of the Patent Issue Division

From: James E. Lake (Tel. 509-624-4276; Fax 509-838-3424)
Wells St. John P.S.
601 W. First Avenue, Suite 1300
Spokane, WA 99201-3828

Sir:

It is hereby requested that a Certificate of Correction be issued with respect to Patent No. 7,160,817 B2, granted January 9, 2007, in accordance with the Certificate of Correction form attached hereto.

It is noted that errors appear in this patent of a typographical nature of character, as more fully described below. The errors occurred in good faith. Correction thereof does not involve such changes in the patent as would constitute new matter or would require re-examination.

Other errors listed on the Certificate of Correction form were apparently incurred through the fault of the PTO as will be disclosed by the records of files in the Office.

Attached hereto is Form PTO-1050 being suitable for printing.

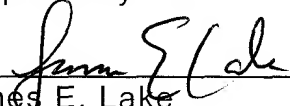
The exact page and line number where the errors occur in the application file are:

Paragraph 25, Line 10

Paragraph 28, Line 9

Please charge Deposit Account No. 23-0925 the amount of \$100.00, as required by 37 CFR 1.20(a).

Dated: 31 Jul 2001

Respectfully submitted,
By: 
James E. Lake
Reg. No. 44,854

UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

PATENT NO. : 7,160,817 B2

DATED : January 9, 2007

INVENTOR(S) : Marsh

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title (54) – Replace “Dielectric Material Forming Methods” with --Dielectric Material Forming Methods and Enhanced Dielectric Materials--.

Column 4, Line 62 – Replace “greater that of” with --greater than that of--.

Column 5, Line 31 – Replace “approximately evening” with --approximately evenly--.

Column 8, Line 13 – Replace “yield a hdielectric” with --yield a dielectric--.

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1 of 1

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Patent No. 7,160,817 B2